## In the Claims:

- (Currently Amended) An electronic component comprising: 1.
  - a wafer:
  - a plurality of bond pads disposed on a surface of the wafer;
- a plurality of functional 3-D structures disposed on the surface of the wafer, such that each bond pad is laterally spaced from the plurality of bond pads so that each bond pad is associated with a laterally-spaced one of the 3-D structures, each functional 3-D structure including a non-conductive compliant base element and having an upper surface spaced from the surface of the wafer,

a plurality of reroute traces, each reroute trace extending over the surface of the wafer between a bond pad and its associated 3-D structure such that [[,]] each reroute trace [[being]] is electrically connected to one of the bond pads and extending extends onto the upper surface of the associated laterally-spaced one of the functional 3-D structures so that the reroute trace provides an electrical connection between the bond pad and the upper surface of the associated functional 3-D structure; and

a plurality of selected 3-D structures disposed on the surface of the wafer to provide a mechanical reinforcement, wherein at least some of the selected 3-D structures have a greater mechanical load-bearing capacity than some of the functional 3-D structures.

(Original) The component of claim 1 wherein each reroute trace comprises a 2. copper/nickel layer that is covered by a gold layer.

- 3. (Original) The component of claim 1 wherein the selected 3-D structures have a lower degree of compressibility than the functional 3-D structures.
- 4. (Previously Presented) The component of claim 1 wherein the selected 3-D structures have a greater height than the functional 3-D structures.
- 5. (Previously Presented) The component of claim 1 wherein each of the selected 3-D structures includes a compliant base element that has a greater volume than the compliant base element of the functional 3-D structures.
- 6. (Withdrawn) The component of claim 1 wherein each of the selected 3-D structures is protected by a metal cap.
- (Withdrawn) The component of claim 1 wherein each of the selected 3-D structures is surrounded by a metallic supporting ring.
- 8. (Original) The component of claim 1 wherein the selected 3-D structures are arranged in a regularly distributed manner in an edge region of the wafer.
- 9. (Original) The component of claim 1 wherein the selected 3-D structures are arranged in a regularly distributed manner over the wafer.
- 10. (Original) The component of claim 1 wherein the selected 3-D structures are able to be electrically bonded.

11. (Withdrawn) The component of claim 1, wherein each of the other 3-D structures have a support structure formed upon a surface of the 3-D structure.

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- 12. (Withdrawn) The component of claim 11 wherein the support structure comprises a metal cap disposed over an entire upper surface of the other 3-D structures.
- 13. (Withdrawn) The component of claim 11 wherein the support structure comprises a metal ring formed along side surfaces of the other 3-D structures.
- 14. (Withdrawn) The component of claim 13 wherein the metal ring is not disposed on any portion of an upper surface of the other 3-D structures.
- 15. (Withdrawn) The component of claim 11 wherein the support structure is formed from the same material as the reroute traces.
- 16. (Withdrawn) The component of claim 11 wherein each reroute trace comprises a copper/nickel layer that is covered by a gold layer.
- 17. (Withdrawn) The component of claim 11 wherein the other 3-D structures have a lower degree of compressibility than the functional 3-D structures.
- 18. (Withdrawn) The component of claim 11 wherein the other 3-D structures have a greater height than the functional 3-D structures.

- 19. (Withdrawn) The component of claim 11 wherein each of the other 3-D structures includes a compliant base element that has a greater volume than the compliant base element of the functional 3-D structures.
- 20. (Withdrawn) The component of claim 11 wherein the other 3-D structures are arranged in a regularly distributed manner in an edge region of the wafer.
- 21. (Withdrawn) The component of claim 11 wherein the other 3-D structures are arranged in a regularly distributed manner over the wafer.

22-27. (Canceled)

- 28. (Previously Presented) An electronic component comprising:
  - a wafer;
  - a plurality of bond pads disposed on the wafer;
- a plurality of functional 3-D structures disposed on the wafer, each functional 3-D structure including a compliant base element and having a first height;
- a plurality of reroute traces, each reroute trace being electrically connected to one of the bond pads and extending onto a surface of one of the functional 3-D structures;
- a plurality of other 3-D structures disposed on the wafer to provide a mechanical reinforcement, each of the other 3-D structures having a second height that is greater than the first height.

29. (Withdrawn) The electronic component of claim 28 wherein the other 3-D structures include a metal cap disposed over an entire upper surface of the other 3-D structures.

- 30. (Withdrawn) The electronic component of claim 28 wherein the other 3-D structures include a metal ring formed along side surfaces of the other 3-D structures.
- 31. (Previously Presented) The electronic component of claim 28 wherein the other3-D structures have a lower degree of compressibility than the functional 3-D structures.
- 32. (Previously Presented) The electronic component of claim 28 wherein the other 3-D structures are arranged in a regularly distributed manner in an edge region of the wafer.
- 33. (Previously Presented) The electronic component of claim 28 wherein the other3-D structures are arranged in a regularly distributed manner over the wafer.
- 34. (Previously Presented) The electronic component of claim 1, wherein the compliant base element is formed from silicone.